

# EE 320 Electronics

Feb. 24

lecture 9

Q4

a) n-type

b)  $N = 10^{16}$  electrons/cm<sup>3</sup>

$$p = \frac{N_i^2}{N} = \frac{10^{20}}{10^6}$$

(assuming complete ionizations)

1  
0000000000000001

$$p = 10,000 \text{ holes/cm}^3$$

c)  $\rho = \frac{1}{q(N \cdot \mu_n + p \cdot \mu_p)}$ ,  $\mu_n = 600 \frac{\text{cm}^2}{\text{V}\cdot\text{s}}$   
 $\Omega \cdot \text{cm}$

$$\rho = \frac{1}{1.6 \times 10^{-19} \cdot 10^{16} \cdot 600}$$

d)  $t = 54 \mu\text{m}$  ,  $L = 200 \mu\text{m}$   
 $w = 10 \mu\text{m}$

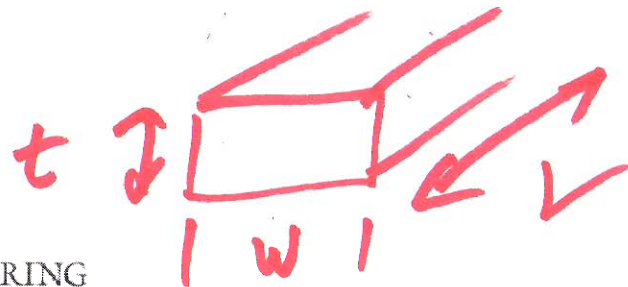
$$R = \frac{\rho}{t} \cdot \frac{L}{w}$$

54

e)  $I = \frac{V}{R} = \frac{1}{R}$

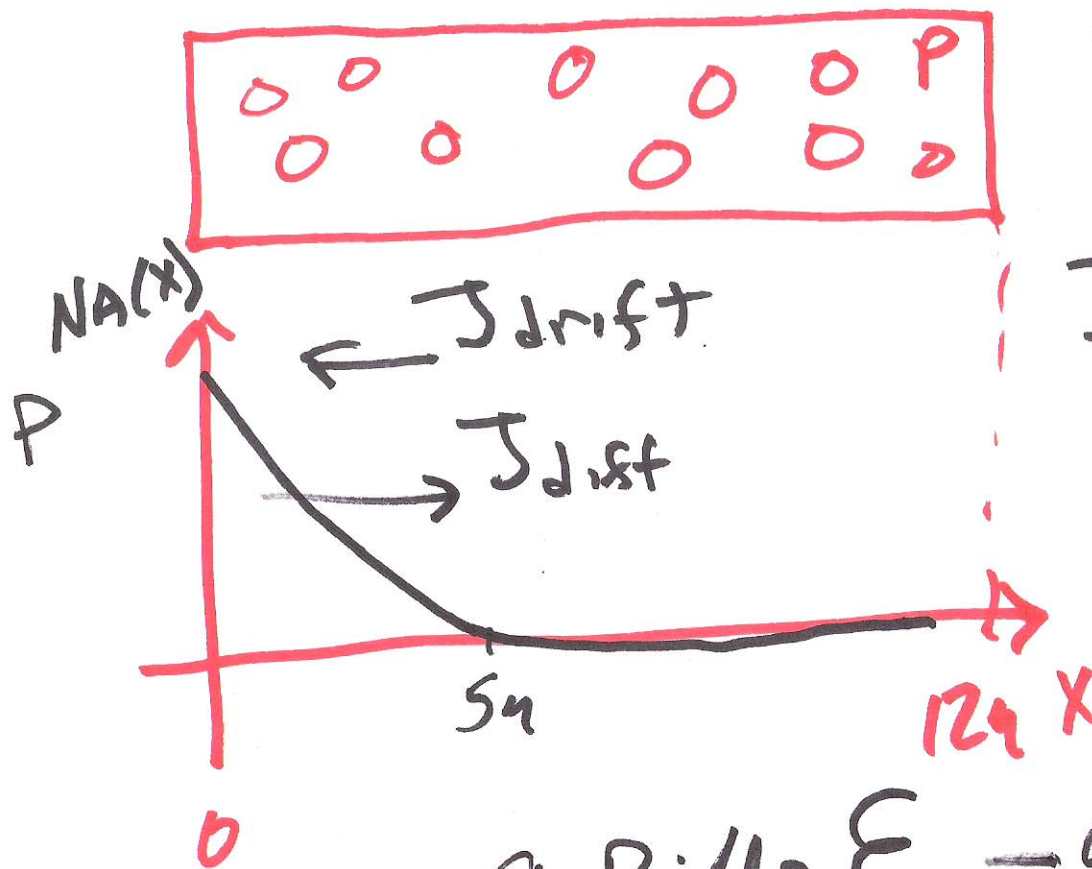
00000050  
                      
 0.0005 cm  
 0.000005 m  
                      
 $\times 10^2 \cdot 10^{-2}$

f)  $J = \frac{I}{A} = \frac{I}{w \cdot t}$



2)

$$3.12) N_A(x) = 10^{18} \cdot e^{-x/14\mu\text{m}} = p(x)$$



$$\frac{dp}{dx} = \frac{10^{-18}}{\text{cm}^3} \left( \frac{-1}{10^{-6}} \right) e^{-x/14\mu\text{m}}$$

$$J_p = J_{\text{drift}} - J_{\text{diff}} = 0$$

$$q p \cdot \mu_p E - q D_p \cdot \frac{dp}{dx} = 0$$



$$10^{18} e^{-x/10^{-6}} \cdot 4p \cdot \Sigma(x) = 0.025 \cdot 4p \cdot \left( -10^{-12} \cdot e^{-x/10^{-6}} \right)$$

$$\begin{aligned} \Sigma(x) &= \frac{-0.025 \cdot 10^{-12}}{10^{18} \cdot 10^{-4} \text{ cm}} \\ &= \frac{-0.025 \cdot 10^{-12}}{10^{14} \text{ cm}} \end{aligned}$$

4)

$$q \cdot p \cdot \mu_p \cdot \mathcal{E}(x) = q \cdot V_T \cdot \mu_p \cdot \frac{dp}{dx}$$

$$p = 10^{18} e^{-x/14\mu\text{m}} \text{ holes/cm}^3$$

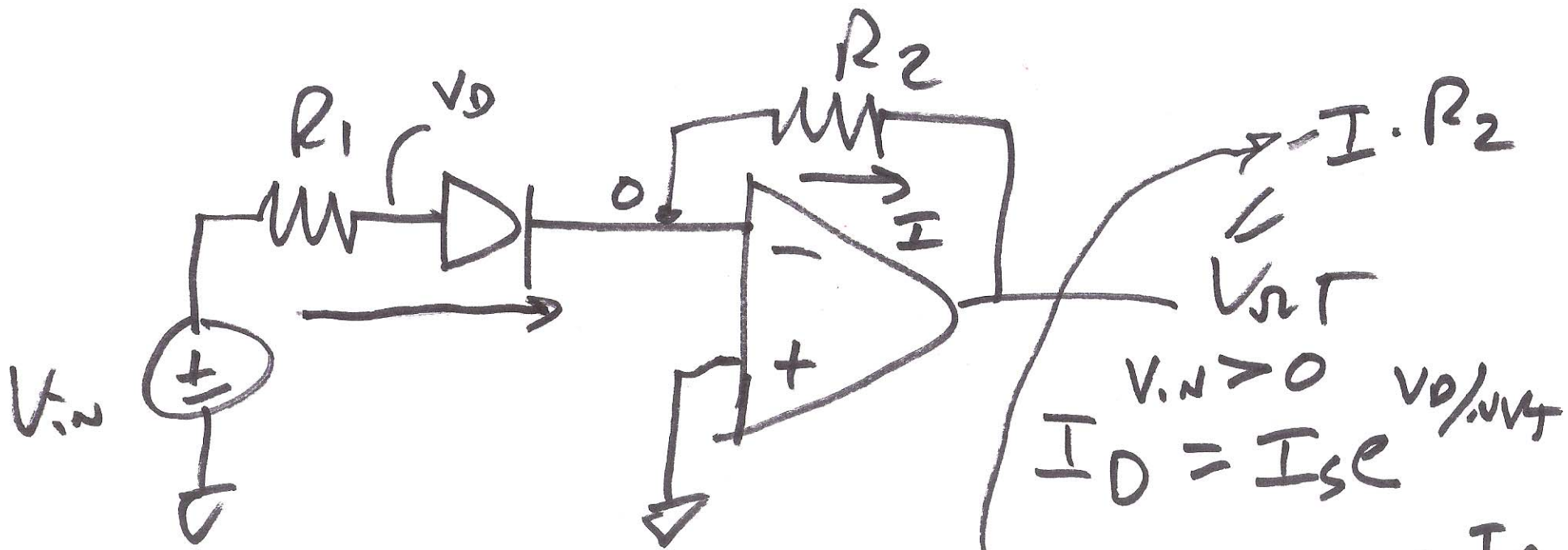
$$\frac{dp}{dx} = \frac{10^{18}}{\text{cm}^3} \left( -\frac{1}{10^{-6}} \right) e^{-x/14\mu\text{m}}$$

$$\frac{10^{18} e^{-x/14\mu\text{m}}}{\text{cm}^3} \cdot \mathcal{E}(x) = 0.025 \frac{10^{18}}{\text{cm}^3} \left( -\frac{1}{10^{-6}} \right) e^{-x/14\mu\text{m}}$$

$$\mathcal{E}(x) = -0.025 \cdot 10^6 / \text{m}$$

$$= -25 \text{ KV/m}$$

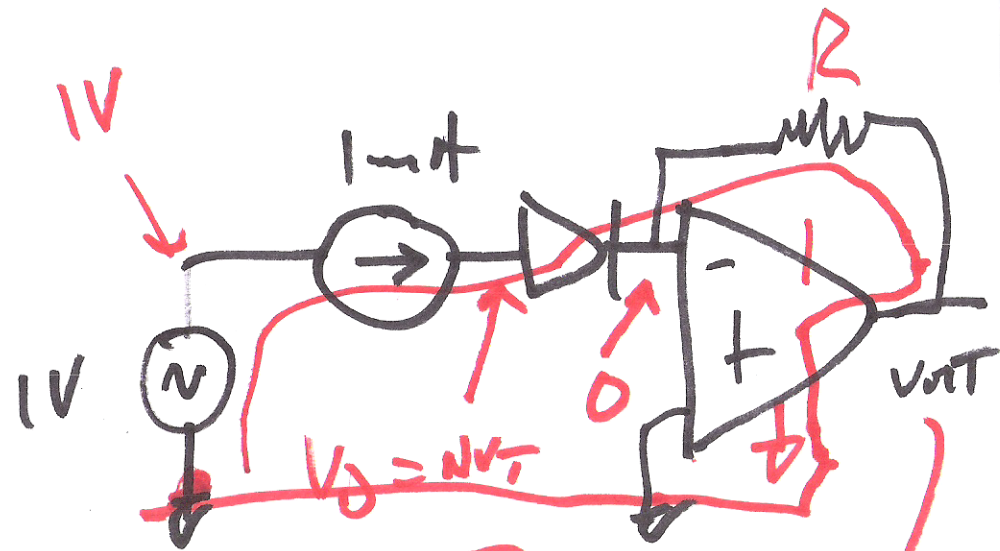
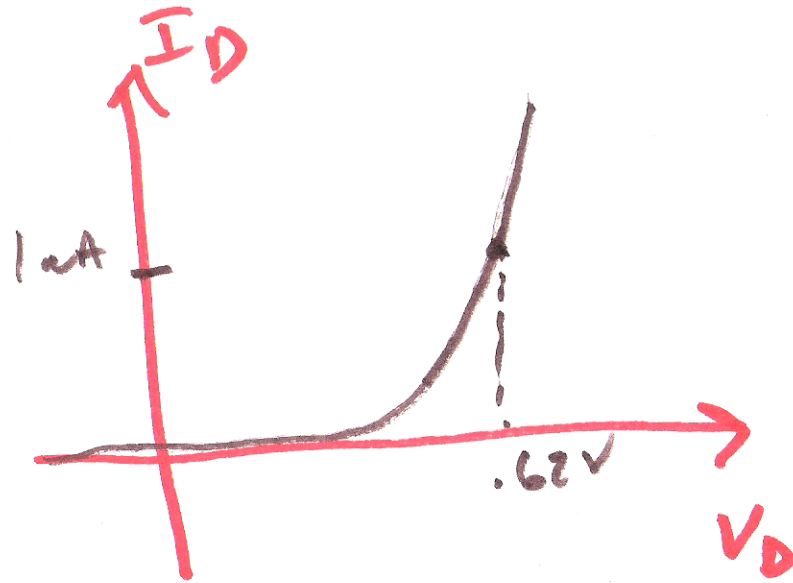
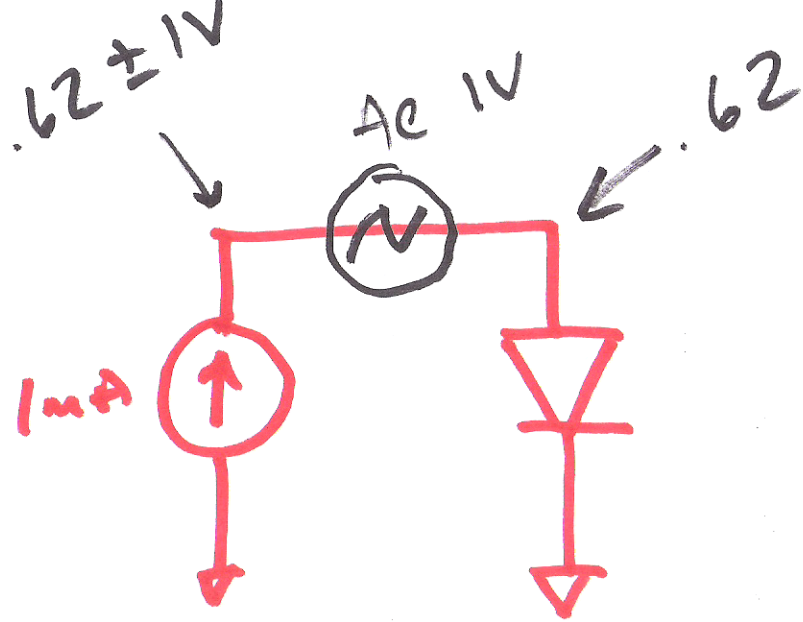
$$\boxed{= -250 \text{ V/cm}} \quad \text{CMOSedu.com}$$



$V_{in} > 0$   
 $V_D = V_{sat}$   
 $I_D = I_S e^{V_D / nV_T}$   
 $V_D = nV_T \ln \frac{I_D}{I_S}$

$$\begin{aligned}
 I &= \frac{V_{in} - V_D}{R_1} \\
 &= \frac{V_{in} - nV_T \ln \frac{I_D}{I_S}}{R_1}
 \end{aligned}$$

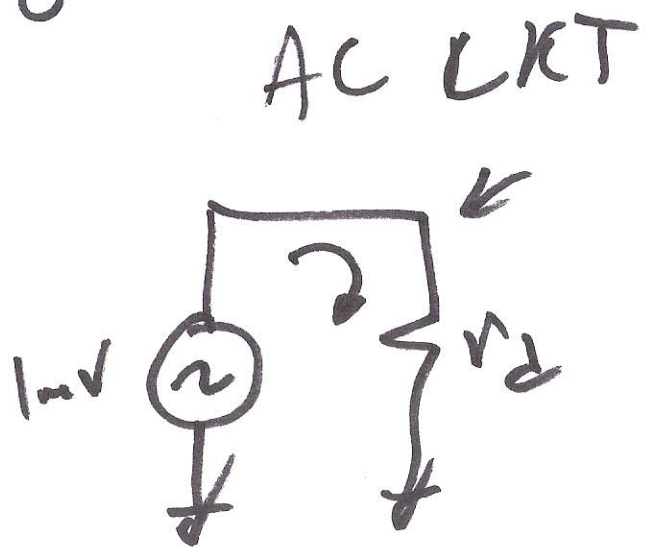
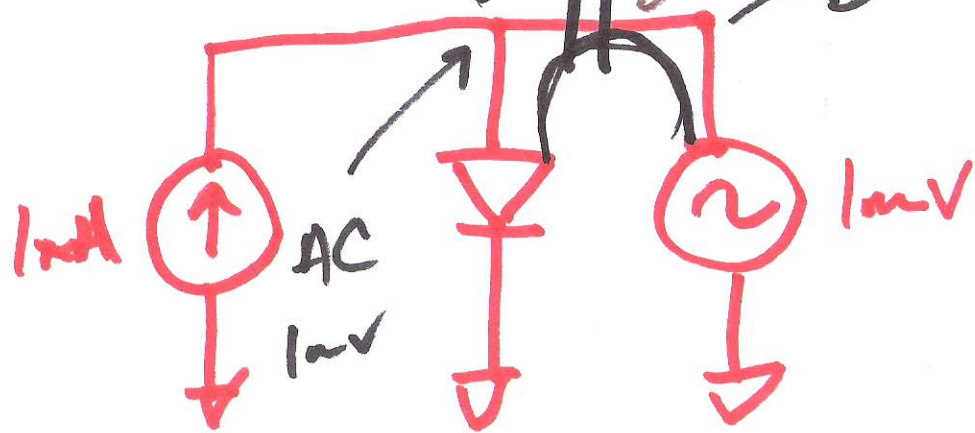
9)



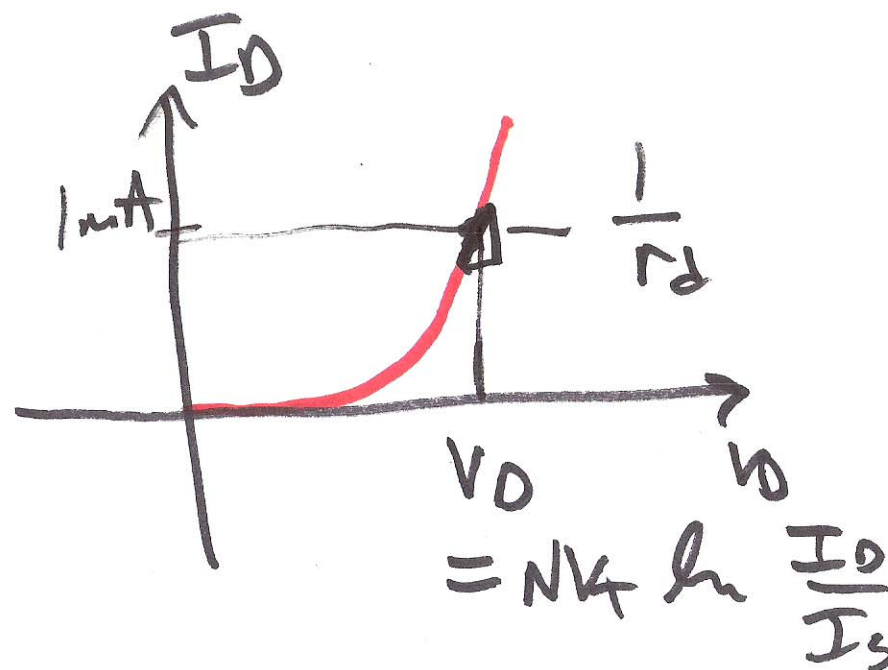
$$\ln \frac{I_D}{I_S} = 0.7$$

$$V_{OLT} = -1mA \cdot R$$

$NkT/q \ln \frac{I_D}{I_S} = V_D$ 
 $\beta I_S$ 
 $1mV$ 
 $DC = 0$

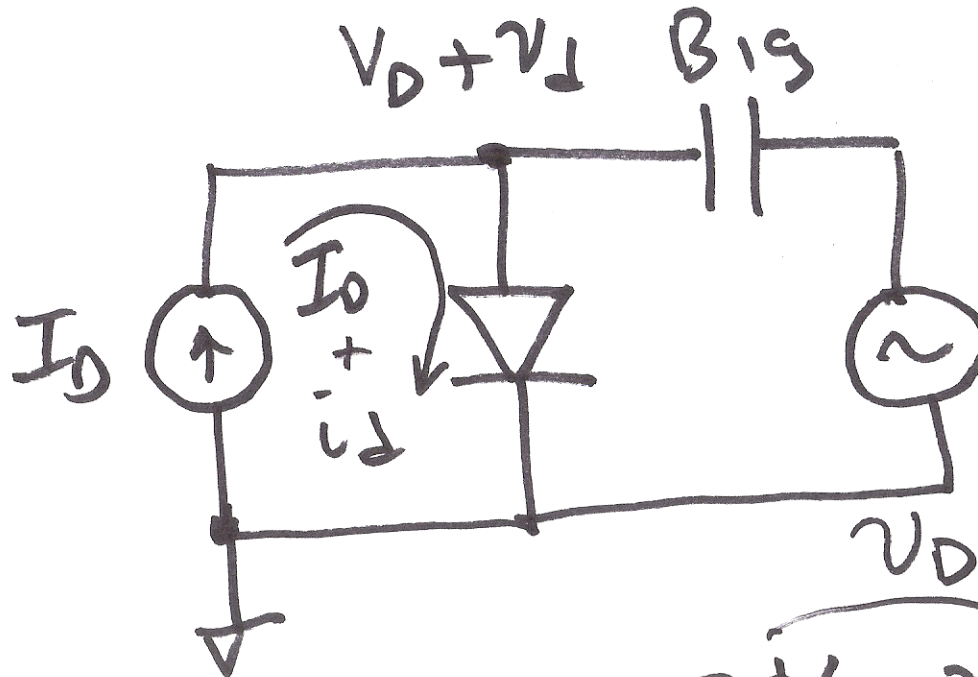


$i_D = \frac{1mV}{R_D}$



8)





$v_x \ll V_D$   
 $v_D + v_d = NV_T \ln \frac{I_D + i_d}{I_S}$   
 $r_d \approx \frac{dV}{dI} = \frac{NV_T}{I_D}$

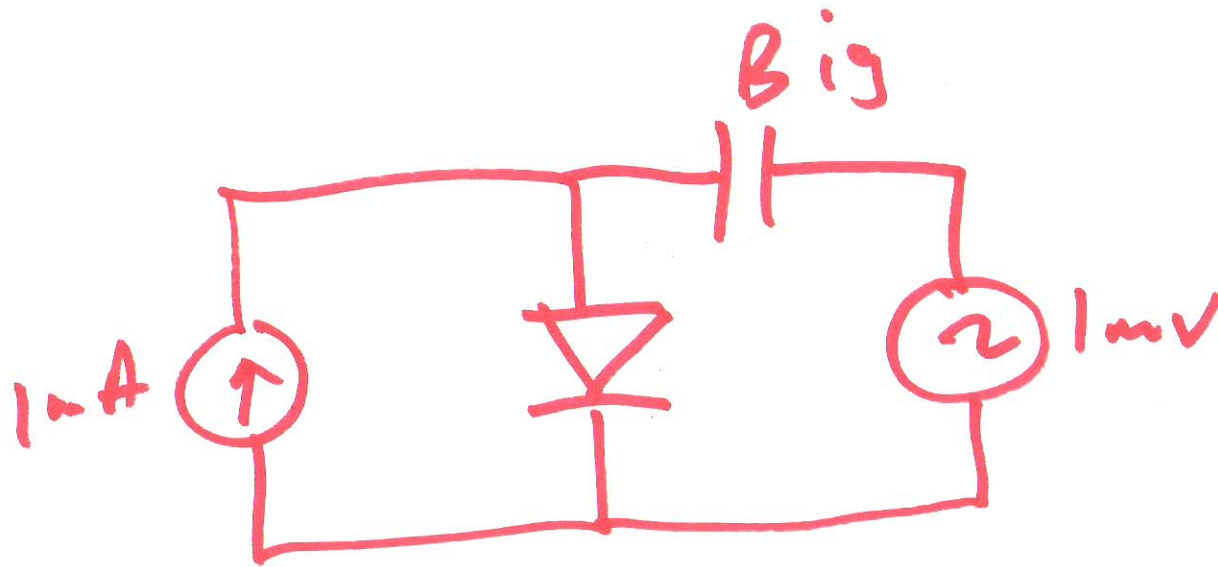
$$r_d = \frac{\delta(V_D + v_d)}{\delta(I_D + i_d)} = \frac{NV_T}{I_D + i_d}$$

$$r_d \approx \frac{NV_T}{I_D}$$

$i_d \ll I_D$   
 Small-signal  
 $I_D = \text{const}$   
 $V_D = \text{const}$

$\frac{d r_x}{d x} = \frac{1}{x}$

9)



find AC current

$$i_d = \frac{1\mu\text{V}}{25\Omega} = 40\mu\text{A}$$

through the diode  
verify with  
Sims.

